

EPISTAR

ES-SMHRPX28C
AlGaInP PX-series LED Chip

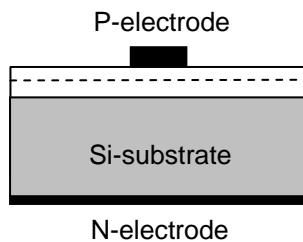
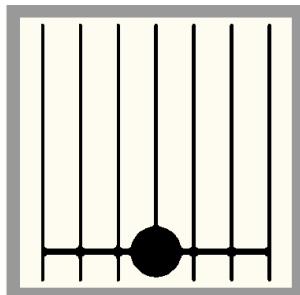
> Mechanical Specification:

(1) Dimension

- Chip size: 28 mil x 28 mil ($710\pm25 \mu\text{m} \times 710\pm25 \mu\text{m}$)
- Thickness: 8.8 mil ($225\pm25 \mu\text{m}$)
- P bonding pad: 4.7 mil ($120\pm10 \mu\text{m}$)

(2) Metallization

- Topside P electrode: Au alloy
- Backside N electrode: Au alloy



Features:

- High luminous intensity
- Thin film structure
- Vertical electrode
- High driving current

Applications:

- Traffic signal
- Lighting

> Electro-optical Characteristics at 25°C:

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	Vf1	If = 10μA	1.35	-	-	V
	Vf2	If = 250mA	-	2.2	2.6	V
Reverse Current	Ir	Vr = 10V	-	-	5.0	μA
Peak Wavelength	λp	If = 250mA	-	631	-	nm
Dominant Wavelength⁽¹⁾	λd	If = 250mA	619	624	629	nm
Spectra Half-width	Δλ	If = 250mA	-	18	-	nm
Luminous Intensity⁽²⁾⁽³⁾	Iv	H13	If = 250mA	9000	-	mcd
		H14		11000	-	

Note:

(1) Basically, the wavelength span is 10nm; however, customers' special requirements are also welcome.

(2) Customers' special requirements are also welcome.

(3) Luminous intensity is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	T _a = 25°C	≤ 350	mA
Reverse Voltage	V _r	T _a = 25°C	≤ 10	V
Junction Temperature	T _j	-	≤ 125	°C
Storage Temperature	T _{stg}	Chip	-40 ~ +85	°C
		Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MPCB) without an encapsulant.
Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 – Relative luminous Intensity vs. Forward Current

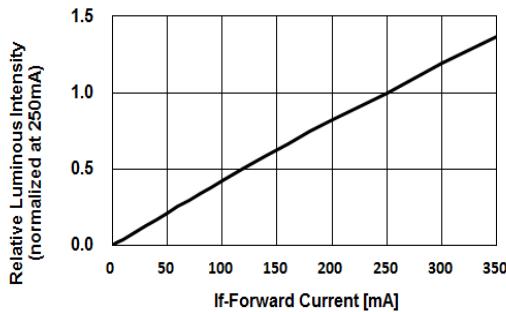


Fig.2 – Forward Current vs. Forward Voltage

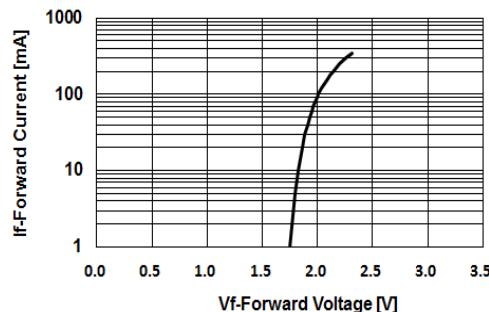


Fig.3 – Relative Intensity (@250mA) vs. Ambient Temperature

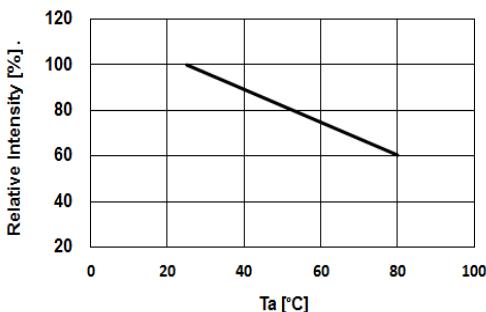


Fig.4 – Forward Voltage (@250mA) vs. Ambient Temperature

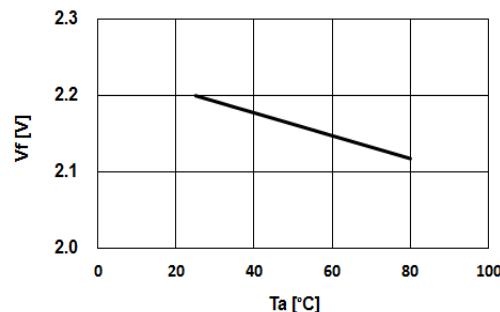


Fig.5 – Dominant Wavelength (@250mA) vs. Ambient Temperature

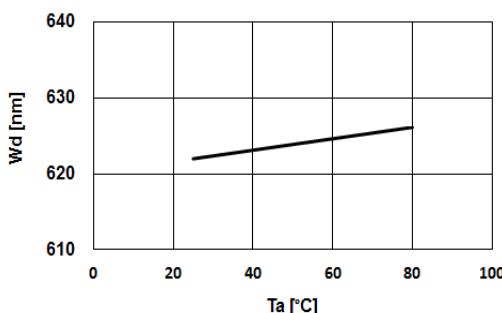


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on T_j max. = 125°C)

